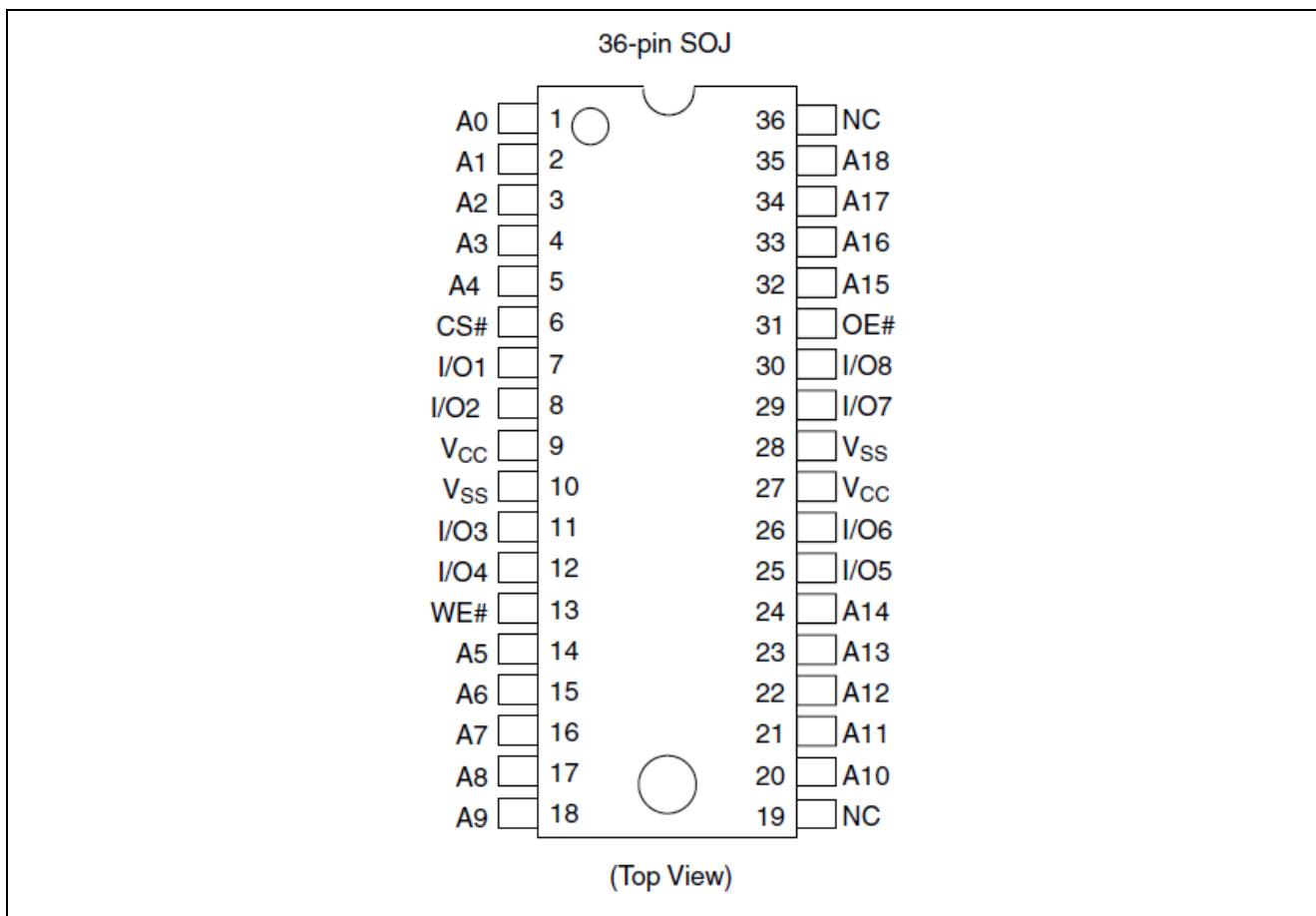


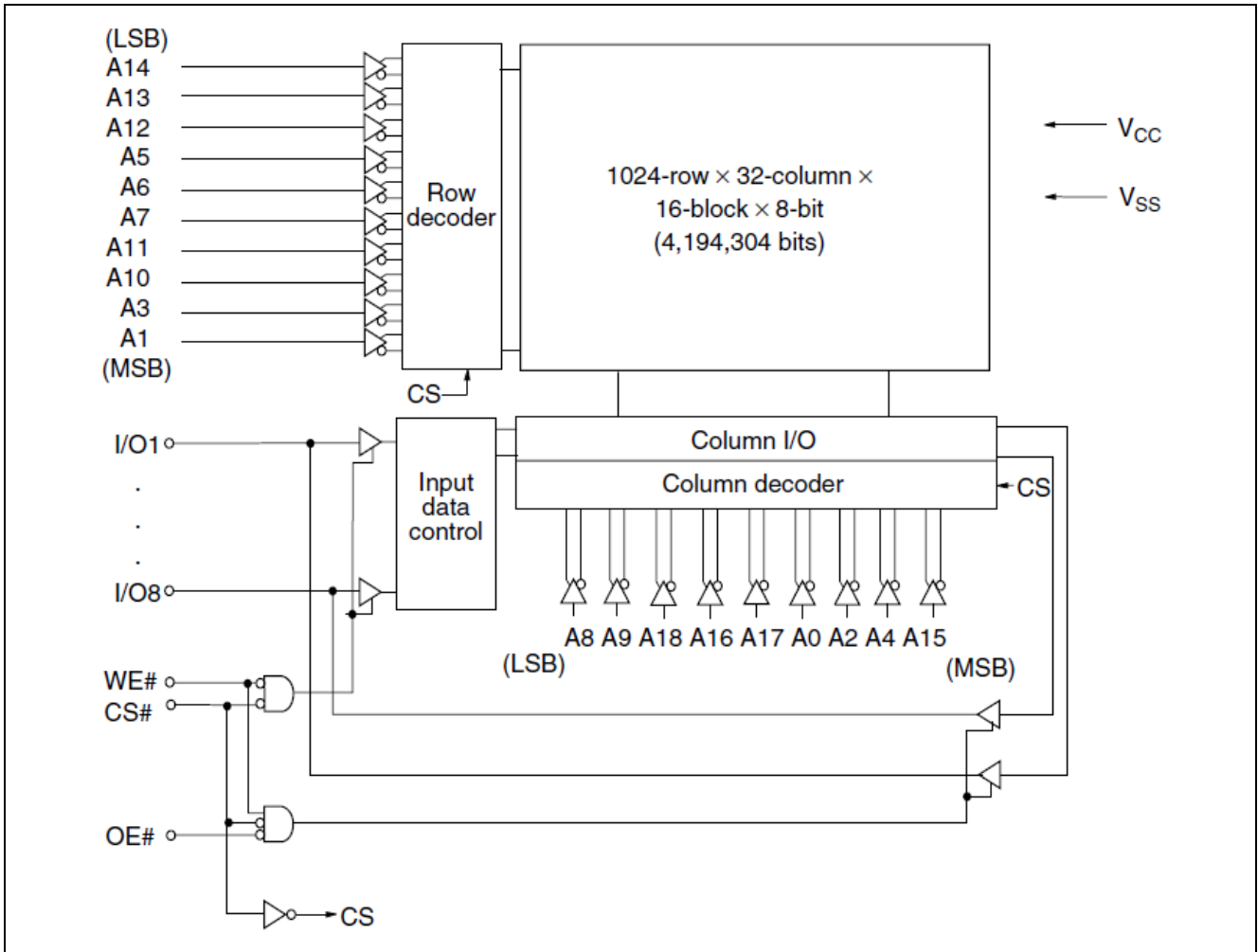
Pin Arrangement



Pin Description

Pin name	Function
A0 to A18	Address input
I/O1 to I/O8	Data input/output
CS#	Chip select
OE#	Output enable
WE#	Write enable
V _{CC}	Power supply
V _{SS}	Ground
NC	No connection

Block Diagram



Operation Table

CS#	OE#	WE#	Mode	V _{CC} current	I/O	Ref. cycle
H	×	×	Standby	I _{SB} , I _{SB1}	High-Z	—
L	H	H	Output disable	I _{CC}	High-Z	—
L	L	H	Read	I _{CC}	DOUT	Read cycle (1) to (3)
L	H	L	Write	I _{CC}	DIN	Write cycle (1)
L	L	L	Write	I _{CC}	DIN	Write cycle (2)

Note: H: V_{IH}, L: V_{IL}, ×: V_{IH} or V_{IL}

Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Supply voltage relative to V _{SS}	V _{CC}	-0.5 to +4.6	V
Voltage on any pin relative to V _{SS}	V _T	-0.5* ¹ to V _{CC} + 0.5* ²	V
Power dissipation	P _T	1.0	W
Operating temperature	T _{opr}	0 to +70	°C
Storage temperature	T _{stg}	-55 to +125	°C
Storage temperature under bias	T _{bias}	-10 to +85	°C

Notes: 1. V_T (min) = -2.0V for pulse width (under shoot) ≤ 6ns.
2. V_T (max) = V_{CC} + 2.0V for pulse width (over shoot) ≤ 6ns.

Recommended DC Operating Conditions

(T_a = 0 to +70°C)

Parameter	Symbol	Min	Typ	Max	Unit
Supply voltage	V _{CC} * ³	3.0	3.3	3.6	V
	V _{SS} * ⁴	0	0	0	V
Input voltage	V _{IH}	2.0	—	V _{CC} + 0.5* ²	V
	V _{IL}	-0.5* ¹	—	0.8	V

Notes: 1. V_{IL} (min) = -2.0V for pulse width (under shoot) ≤ 6ns.
2. V_{IH} (max) = V_{CC} + 2.0V for pulse width (over shoot) ≤ 6ns.
3. The supply voltage with all V_{CC} pins must be on the same level.
4. The supply voltage with all V_{SS} pins must be on the same level.

DC Characteristics(Ta = 0 to +70°C, V_{CC} = 3.3V ± 0.3V, V_{SS} = 0V)

Parameter	Symbol	Min	Max	Unit	Test conditions
Input leakage current	I _{LI}	—	2	μA	V _{IN} = V _{SS} to V _{CC}
Output leakage current	I _{LO}	—	2	μA	V _{IN} = V _{SS} to V _{CC}
Operating power supply current	I _{CC}	—	100	mA	Min cycle CS# = V _{IL} , I _{OUT} = 0mA Other inputs = V _{IH} /V _{IL}
Standby power supply current	I _{SB}	—	40	mA	Min cycle, CS# = V _{IH} , Other inputs = V _{IH} /V _{IL}
	I _{SB1}	—	5	mA	f = 0MHz
		—*1	0.8*1	mA	V _{CC} ≥ CS# ≥ V _{CC} - 0.2V, (1) 0V ≤ V _{IN} ≤ 0.2V or (2) V _{CC} ≥ V _{IN} ≥ V _{CC} - 0.2V
Output voltage	V _{OL}	—	0.4	V	I _{OL} = 8mA
	V _{OH}	2.4	—	V	I _{OH} = -4mA

Note: 1. This characteristics is guaranteed only for L-version.

Capacitance

(Ta = +25°C, f = 1.0MHz)

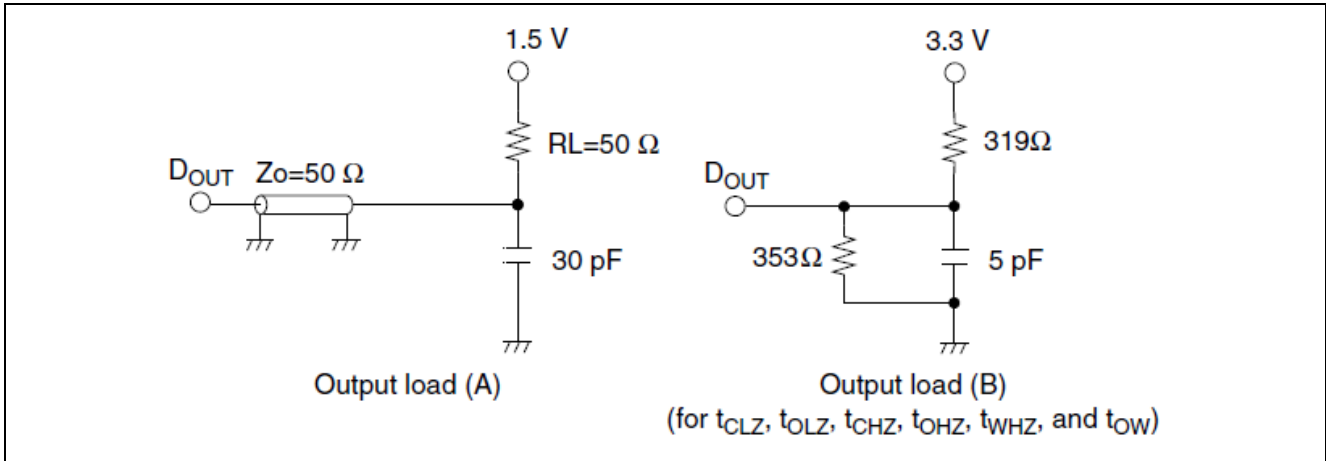
Parameter	Symbol	Min	Max	Unit	Test conditions
Input capacitance*1	C _{IN}	—	6	pF	V _{IN} = 0V
Input/output capacitance*1	C _{I/O}	—	8	pF	V _{I/O} = 0V

Note: 1. This parameter is sampled and not 100% tested.

AC Characteristics

Test Conditions ($T_a = 0$ to $+70^\circ\text{C}$, $V_{CC} = 3.3\text{V} \pm 0.3\text{V}$, unless otherwise noted.)

- Input pulse levels: 3.0V/0.0V
- Input rise and fall time: 3ns
- Input and output timing reference levels: 1.5V
- Output load: See figures (Including scope and jig)



Read Cycle

Parameter	Symbol	R1RW0408D		Unit	Notes
		Min	Max		
Read cycle time	t_{RC}	12	—	ns	
Address access time	t_{AA}	—	12	ns	
Chip select access time	t_{ACS}	—	12	ns	
Output enable to output valid	t_{OE}	—	6	ns	
Output hold from address change	t_{OH}	3	—	ns	
Chip select to output in low-Z	t_{CLZ}	3	—	ns	1
Output enable to output in low-Z	t_{OLZ}	0	—	ns	1
Chip deselect to output in high-Z	t_{CHZ}	—	6	ns	1
Output disable to output in high-Z	t_{OHZ}	—	6	ns	1

Write Cycle

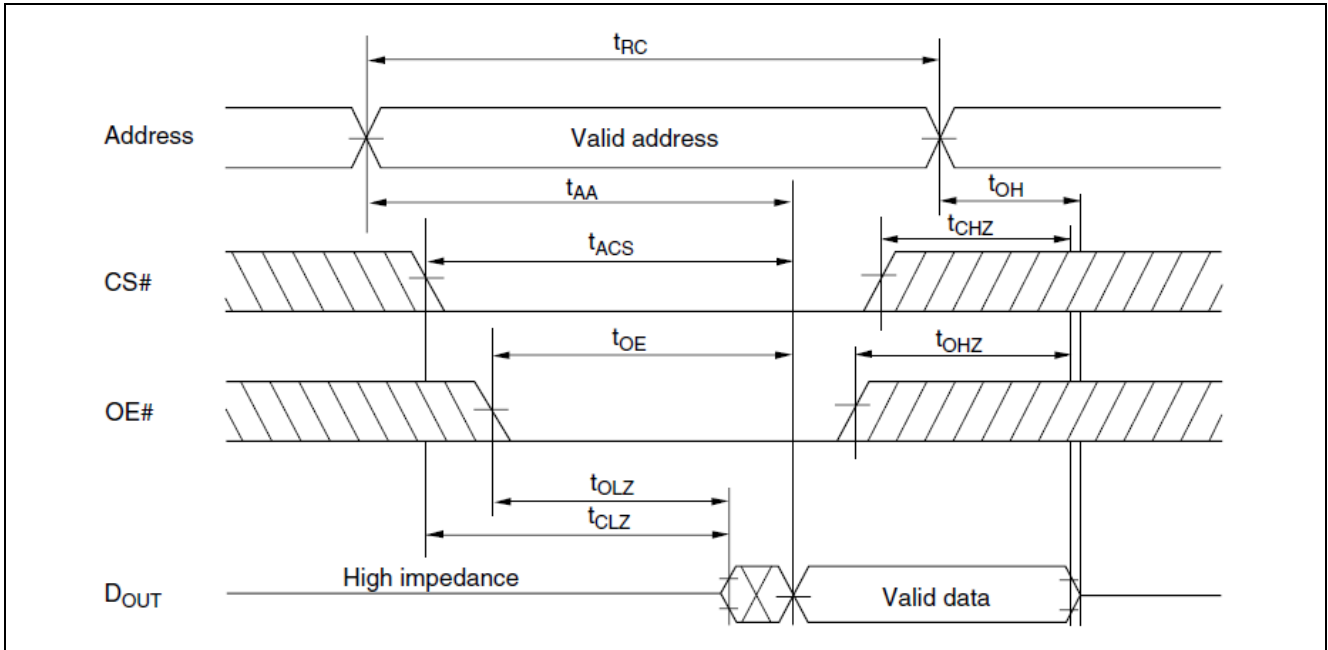
Parameter	Symbol	R1RW0408D		Unit	Notes
		Min	Max		
Write cycle time	t_{WC}	12	—	ns	
Address valid to end of write	t_{AW}	8	—	ns	
Chip select to end of write	t_{CW}	8	—	ns	9
Write pulse width	t_{WP}	8	—	ns	8
Address setup time	t_{AS}	0	—	ns	6
Write recovery time	t_{WR}	0	—	ns	7
Data to write time overlap	t_{DW}	6	—	ns	
Data hold from write time	t_{DH}	0	—	ns	
Write disable to output in low-Z	t_{OW}	3	—	ns	1
Output disable to output in high-Z	t_{OHZ}	—	6	ns	1
Write enable to output in high-Z	t_{WHZ}	—	6	ns	1

Notes: 1. Transition is measured $\pm 200\text{mV}$ from steady voltage with output load (B). This parameter is sampled and not 100% tested.

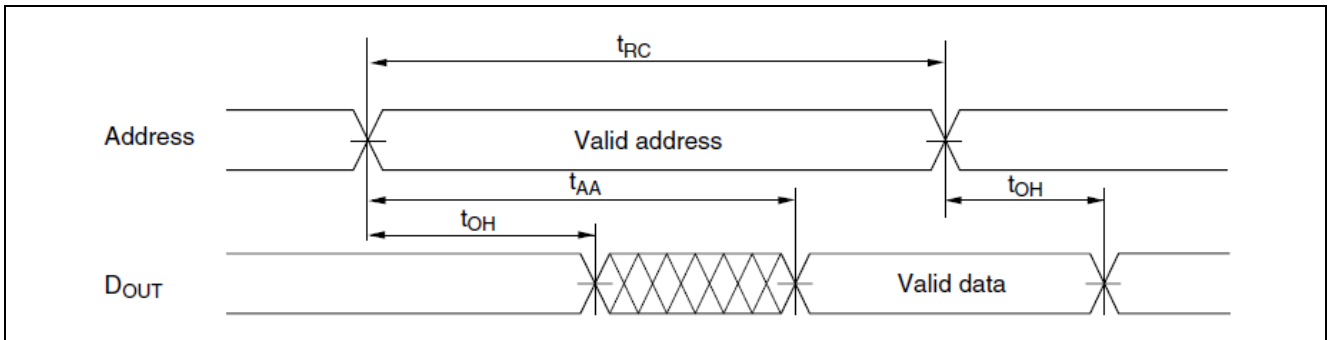
2. Address should be valid prior to or coincident with CS# transition low.
3. WE# and/or CS# must be high during address transition time.
4. If CS# and OE# are low during this period, I/O pins are in the output state. Then, the data input signals of opposite phase to the outputs must not be applied to them.
5. If the CS# low transition occurs simultaneously with the WE# low transition or after the WE# transition, output remains a high impedance state.
6. t_{AS} is measured from the latest address transition to the later of CS# or WE# going low.
7. t_{WR} is measured from the earlier of CS# or WE# going high to the first address transition.
8. A write occurs during the overlap of a low CS# and a low WE#. A write begins at the latest transition among CS# going low and WE# going low. A write ends at the earliest transition among CS# going high and WE# going high. t_{WP} is measured from the beginning of write to the end of write.
9. t_{CW} is measured from the later of CS# going low to the end of write.

Timing Waveforms

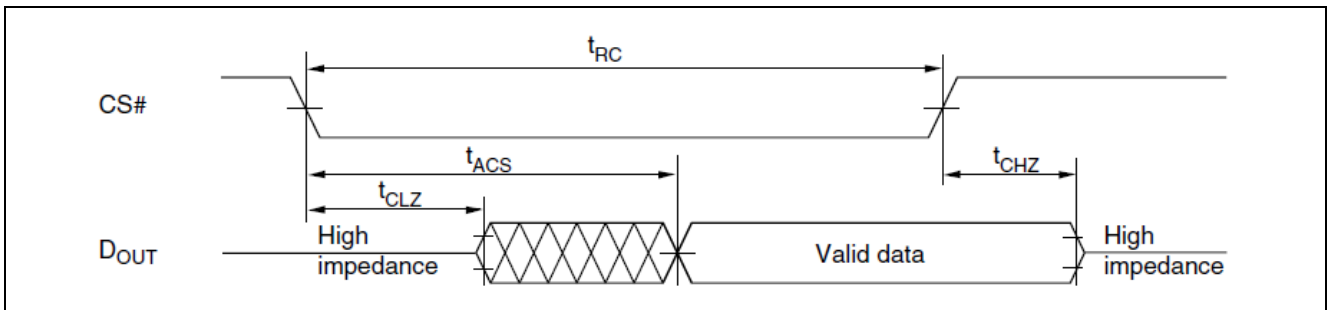
Read Timing Waveform (1) (WE# = V_{IH})



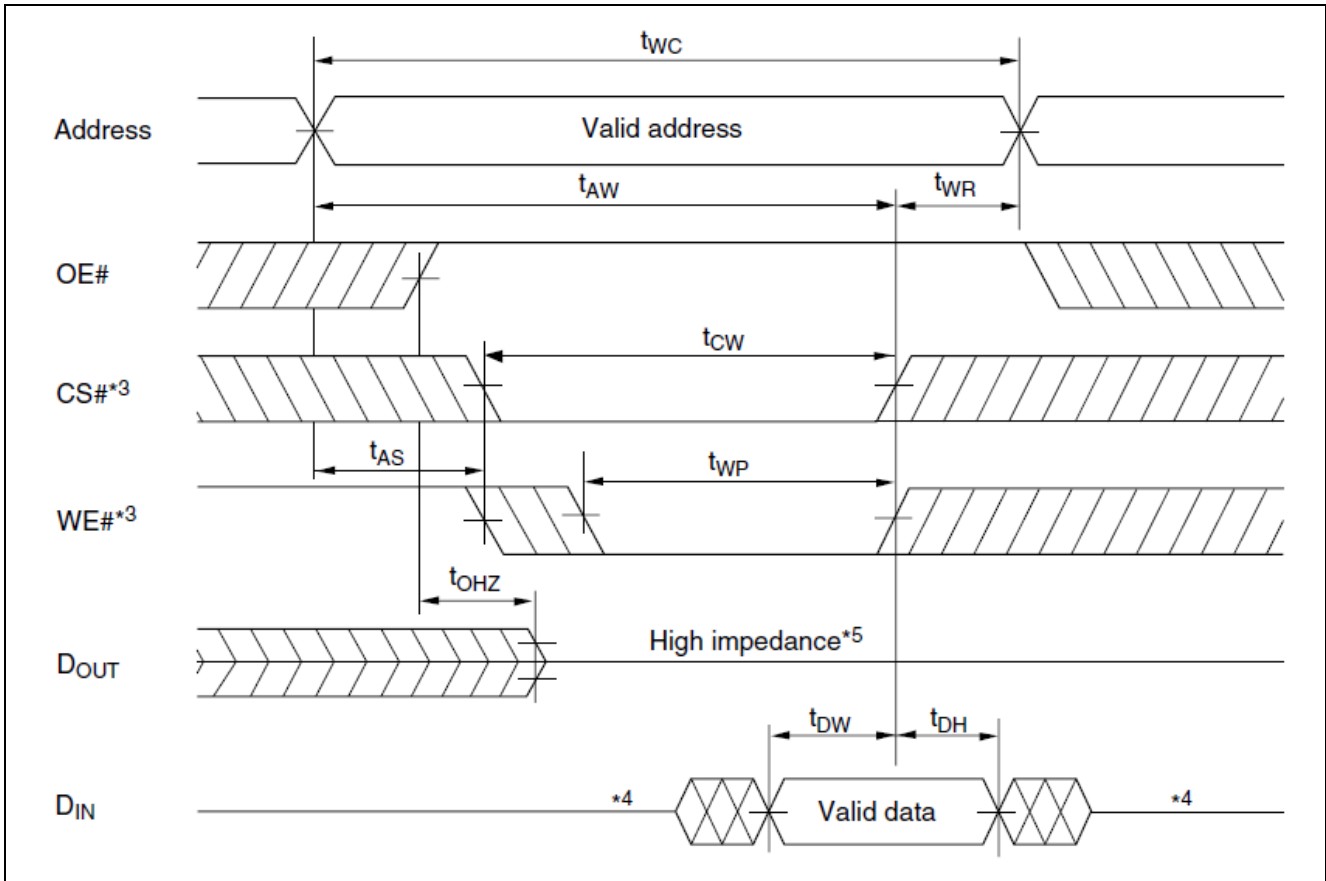
Read Timing Waveform (2) (WE# = V_{IH}, LB# = V_{IL}, UB# = V_{IL})



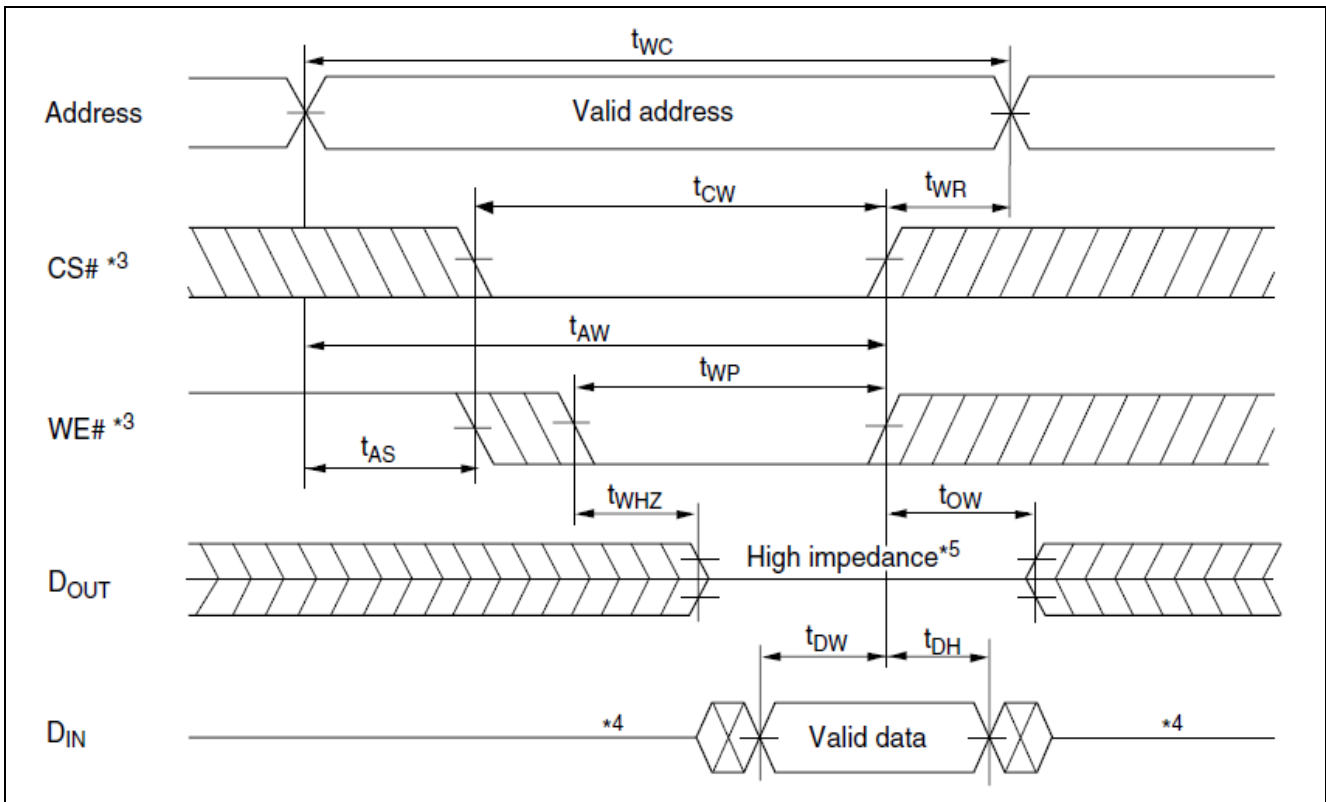
Read Timing Waveform (3) (WE# = V_{IH}, CS# = V_{IL}, OE# = V_{IL})*2



Write Timing Waveform (1) (WE# Controlled)



Write Timing Waveform (2) (CS# Controlled)



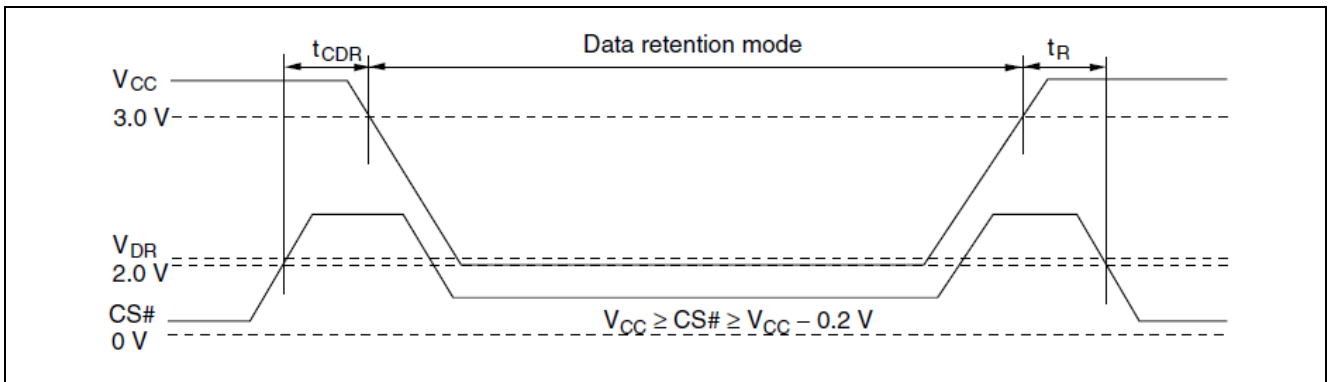
Low V_{CC} Data Retention Characteristics

(T_a = 0 to +70°C)

This characteristics is guaranteed only for L-version.

Parameter	Symbol	Min	Max	Unit	Test conditions
V _{CC} for data retention	V _{DR}	2.0	—	V	V _{CC} ≥ CS# ≥ V _{CC} - 0.2V, (1) 0V ≤ V _{IN} ≤ 0.2V or (2) V _{CC} ≥ V _{IN} ≥ V _{CC} - 0.2V
Data retention current	I _{CCDR}	—	400	μA	V _{CC} = 3V V _{CC} ≥ CS# ≥ V _{CC} - 0.2V, (1) 0V ≤ V _{IN} ≤ 0.2V or (2) V _{CC} ≥ V _{IN} ≥ V _{CC} - 0.2V
Chip deselect to data retention time	t _{CDR}	0	—	ns	See retention waveform
Operation recovery time	t _R	5	—	ms	

Low V_{CC} Data Retention Timing Waveform



Revision History

Rev.	Date	Description	
		Page	Summary
1.00	Nov.18.19	-	First Edition issued

All documents should contain the following section break and paragraph as the last item. The footers of this document refer to the paragraph in order to reference the last page of the document.

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